NSN 5961-00-249-3998

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-249-3998 **Inclosure Material:** Metal **Overall Length:** Between 0.874 inches and 1.030 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.040 inches and 1.060 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 breakover voltage, dc **Current Rating Per Characteristic:** 110.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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